Molar Binding Energy of Zigzag and Armchair Single-Walled Boron Nitride Nanotubes

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ABSTRACT

Molar binding energy of the boron nitride single-walled zigzag and armchair nanotubes is calculated within the quasi-classical approach. We find that, in the range of ultra small radii, the binding energy of nanotubes exhibit an oscillatory dependence on tube radius. Nanotubes (1,1), (3,0), and (4,0) are predicted to be more stable species among single-walled boron nitride nanotubes. The obtained binding energies of BN single-walled nanotubes corrected with zero-point vibration energies lies within the interval (12.01-29.39) eV. In particular, molar binding energy of the ultra-large-radius tube is determined as 22.95 eV. The spread of the molar zero-point vibration energy of BN nanotubes itself is (0.25-0.33) eV and its limit for ultra-large-radius tubes is estimated as 0.31 eV. The binding energy peak located at 2.691 Å corresponds to the equilibrium structural parameter of all realized stable BN nanotubular structures.

Keywords: Binding Energy, Zigzag and Armchair Nanotubes, BN

1. Introduction

Boron nitride with the chemical formula BN can be found in the form of one-dimensional diatomic molecules, two-dimensional nanotubes and fullerenes, three-dimensional crystals like the layered hexagonal h-BN and rhombohedral r-BN as well as turbostratic t-BN, cubic zinc-blende c-BN and wurtzite w-BN modifications as well as their nanostructures etc. Boron and nitrogen atoms are surrounded tetrahedrally in both denser c-BN and w-BN crystals.

Any constituent atom of an h-BN crystal, which is believed to correspond to the boron nitride ground state, may be considered as a 3-coordinated atom because the strong chemical binding (covalent with some deal of ionic) occurs only within the layers, while weak van der Waals forces seem to be responsible mostly for interlayer binding. The h-BN crystal has a “graphitic” structure with a two-layer stacking sequence (r-BN is characterized by a three-layer stacking). These layers consist of regular hexagons (i.e., 6-membered atomic rings) with vertexes alternatively occupied by B and N atoms. In the h-BN crystal, B atoms are placed directly above N atoms and vice versa. Therefore one might suppose that the ionicity contributes to interlayer bonding as well. However, actually, the electrostatic component is insignificant due to the large interlayer distances. It is argued also by the existence of a layered r-BN crystal, in which each subsequent layer is turned around an angle of $\pi / 3$, and also by the isolated plane defects and their bundles included in real h-BN crystals, in which any given atom can be placed above the same atom. In addition, it is possible to obtain turbostratic t-BN and amorphous structures in the form of mixes of various boron nitride crystalline phases, and multi-walled nanotubular and multi-shelled fullerene-like BN structures. Strong chemical bonding between atoms in a given layer and weak interlayer interaction in layered boron nitrides specify an opportunity of physical and chemical intercalations by various atoms and molecules.

Based upon the similarity of structures of the boron nitride layered phases with graphite, it was assumed [1] that along with carbon C nanotubes, stable BN nanotubes – fragments of hexagonal or mixed BN layers wrapped into cylinders – could also exist.

Indeed, by means of arc discharge BN nanotubes had been obtained both from carbon nanotubes [2] and in carbon-free plasma [3]. The arc discharge methods were used to produce $B_xC_yN_z$ nanotubular structures identified by the high-resolution transmission-electron-microscopy
(TEM) together with K-edge electron-energy-loss-spectroscopy (EELS) determining the local atomic composition, while, in a carbon-free plasma discharge area between a BN-packed W-rod and a cooled Cu-electrode, multi-walled pure BN tubes were produced with inner diameters on the order of 1 to 3 nm and with lengths up to 200 nm; EELS of individual tubes yielded B/N ratio of approximately 1.

At present various methods of synthesis of the BN nanotubular structures are developed.

The arc discharge in a molecular nitrogen atmosphere between electrodes made of graphite and refractory boron compounds, e.g., hafnium diboride HfB₂, forms BN-C nanotubes with strong phase separation between BN and C layers along the radial direction [4,5]. If both electrodes are made of HfB₂ rods, single- or double-walled chemically pure BN nanotubes are formed with a structure close to stoichiometric B/N ~1 [6]. Most obtained tube ends are closed by flat layers perpendicular to the tube axis. A closure by a triangular facet resulting from three 120°-disclinations was proposed to account for this specific shape. For the most part, the multi-walled BN nanotubes are formed with electrodes made of zirconium diboride ZrB₂ [7,8]. In this case most of the nanotubes have diameters from 3 to 40 nm and lengths on the order of 100 nm. Single-layer tubes with diameters of 2 to 5 nm are also formed rarely. The morphology of the tube tips suggests the presence of pentagons and heptagons which are energetically less favorable compared with squares.

A laser melting of the solid-state BN (of any crystal structure, not only layered but also amorphous) at high nitrogen pressure, (5-15) GPa, forms nanotubes free from inclusions, containing from 3 up to 8 walls, and having a characteristic outer diameter of (3-15) nm [9].

BN nanotubes have been also obtained by pyrolysis of the molecular precursor with the use of Co catalysts [10]. Bundles of single-walled (or containing few layers) BN nanotubes with almost stoichiometric structure can be formed in substitution reactions – by thermal treatment of a mixture of boron trioxide or trichloride, and bundles of single-walled C-nanotubes at high temperatures, (1250-1350)°C, in a nitrogen flow [11,12].

BN nanotubes also grow in solid-state process that involves neither deposition from the vapor phase nor chemical reactions [13]. The nanotubes were produced by first ball-milling of the layered h-BN powder to generate highly disordered or amorphous nanostructures and followed by the product annealing at temperatures up to 1300°C. The annealing leads to the nucleation and growth of hexagonal BN nanotubes both of cylindrical and bamboo-like morphologies.

Multi-walled BN nanotubes have been obtained by carbothermal reduction of the ultra-dispersive amorphous boron oxide B₂O₃ at simultaneous nitriding at high temperatures, (1100-1450)°C [14,15]. For large tubes, it is found that the ratio of length to radius is preserved.

Besides of arc-melting, pyrolysis, and chemical reactions, boron nitride nanotubular structures were created by means of ballistic nuclear displacements caused in a h-BN layered crystal structure by electron irradiation in TEM [16,17].

High growth temperatures (above 1100°C), a low production yield, and impurities have prevented progress in applications of BN nanotubes in the past decade. Rather recently, it has been shown that these tubes can be grown on substrates at lower temperatures (of about 600°C) [18]. High-order tubular structures were constructed, which can be used without further purification.

For synthesizing BN nanotubular material, some methods were inspired from carbon. In particular, these include techniques such as laser ablation and non-ablative laser heating [19]. Transformation of the compressed powders of the fine-grained h-BN into nanotubular form can be induced [20] by the concentrated light energy in nitrogen flow. Fiber-like clusters synthesized by evaporation of the layered BN in a nitrogen atmosphere and obtained in powders formed on substrate or chamber surfaces contained nanotubes with diameters and lengths equal to (0.05-200) and (100-3000) µm, respectively. Applying TEM, there were obtained their associations in tree- and coral-like aggregates.

BN nanotubes can be grown from a nanococoon seed as well [21].

Recently the development of a new method for producing long, small-diameter, single- and few-walled, BN nanotubes in macroscopic quantities has been reported [22]. The pressurized vapor/condenser (PVC) method produces highly crystalline, very long, small-diameter nanotubes without catalysts. Their palm-sized, cotton-like masses of raw material were grown by this technique and spun directly into centimeters-long yarn. Nanotube lengths were observed to be ~100 times that of those grown by the most closely related method.

Soon after synthesizing the first BN nanotubes, it was proposed a number of their possible applications in technique [3]. For example, a system of the collinear BN nanotubes forms a boron nitride fiber. At the same time, the theory [23] developed for structural and electronic properties of nanotubular heterojunctions, in which one of the layers is nanotubular boron nitride (namely, for C/CN and BC₃N/CN systems), leads to a conclusion that on basis of it a different electronic devices can be designed. In particular, nanostructures with C-layers both in the center and at the periphery separated by a few BN-layers may allow the creation of sandwich nanotubular
devices [4]. Within the special semiempirical approach [24] C/BN superlattices and isolated junctions have been investigated as specific examples by the wide variety of electronic devices that can be realized using such nanotubes. The bottom of the conduction bands in pure BN nanotubes is controlled by a nearly-free-electron-state localized inside the tube suggesting interesting electronic properties under doping.

Other opportunities of application of the BN nanotubes are connected with the features of their phonon spectrum [25]. Such dielectric tubes without inversion center can be used as a phonon laser in GHz – THz range or hypersound quantum generator. Because of the presence of special nanotubular oscillatory modes, there is a strong enhancement of electron-phonon interaction in comparison with a bulk material. It is not excluded that close-packed one-dimensional BN nanotubes will serve as high-temperature superconductors. The GHz oscillatory behavior of double-walled BN nanotubes was also predicted [26,27]. This system can also be employed for making good shock absorbers because application of low pressure leads to its significant compression.

The band gap progression with BN nanotube diameter (which is of crucial importance for device applications) was presented and analyzed in detail in [28]. In zigzag BN nanotubes, radial deformations that give rise to transverse pressures decrease the gap from 5 to 2 eV, allowing for optical applications in the visible range [29]. Importantly, both the zigzag and armchair tubes are predicted [30] (see also [31]) to exhibit large second-order nonlinear optical behavior with the second-harmonic generation and linear electro-optical coefficients being up to 15-times larger than that of bulk BN in both denser zinc-blende and wurtzite structures. This indicates that BN nanotubes are promising materials for nonlinear optical and optoelectronic applications.

The electronic structure of BN nanotubes can be tuned within a wide range through covalent functionalization [32] (see also [33]). The ultraviolet (UV) and visible adsorption spectra indicate that their electronic structure undergoes drastic changes under functionalization. First principle calculations revealed that the covalently functionalized BN nanotubes can be either n- or p-doped depending on the electronegativity of molecules attached. Their energy gap can be adjusted from UV to visible optical range by varying concentration of functionalizing species.

One-dimensional crystals of potassium halides, including KI, KCl, and KBr, were inserted into BN nanotubes [34]. High-resolution TEM and energy-dispersive X-ray spectrometry were used to characterize their microstructures and compositions. The fillings are usually single crystals with lengths up to several μm. The wetting properties (static contact angles of the liquids and surface tension) of individual BN nanotubes were studied [35] experimentally using a nanotube-based force to measure the interactions between nanotubes and liquids in situ.

First principles simulations on the interaction of molecular hydrogen H₂ with the native and substitutional defects in small-diameter (8,0) BN nanotubes were performed in [36]. The adsorption of H₂ in structures found to be endothermic with respect to dissociation, with the small-diameter nanotube possessing the smaller barrier. Although chemisorption along the tube axis is energetically preferred, the barrier for dissociation is lower for chemisorption across the tube axis. This implies that chemisorbed hydrogen can be kinetically trapped in a higher energy state. Dopants that maximize the localization of the higher-occupied-molecular-orbital (HOMO) and lower-unoccupied-molecular-orbital (LUMO) states maximize hydrogen binding energies. C-dopants do not enhance H₂ binding, whereas Si-dopants substituting for N provide H₂ binding energies of 0.8 eV, at the upper end of the range required for hydrogen storage. The formation energy of most defects is reduced with increasing curvature except for the C-substitutionals. Vacancies do not reduce the barriers for H₂ dissociation for strongly curved nanotubes. The surface stress induced by the nanotube curvature boosts the hydrogen storage capabilities of vacancies with the nitrogen vacancy chemisorbing 4H and allowing a H₂ molecule to enter the interior of the tube. The hydrogen binding properties of BN systems strongly depend on existing defects and dopants. Pretreating of these systems so as to partially remove nitrogen should enhance H₂ adsorption properties. The hydrogen absorption capacity of Ti-covered single-walled BN nanotube was investigated using first principles plane-wave (PW) method [37]. The weak interaction of H₂ molecules with the outer surface of bare nanotube can be significantly enhanced upon functionalization by Ti atoms: each Ti atom adsorbed on tube can bind up to four H₂ molecules with average binding energy suitable for room temperature storage.

The morphology of BN nanotubes with a collapsed structure has been discovered by a metal-catalyzed treatment [38]. The collapse causes the dramatic enlargement of a specific surface area of BN nanotubes and remarkably enhances the hydrogen storage capacity of BN nanotubes. It was reported [39] that proteins are immobilized on boron nitride nanotubes. There is a natural affinity of a protein to BN nanotube: it can be immobilized on tube directly, without using of an additional coupling reagent. Besides, boron nitride nanotubes may be dissolved in organic solvents by wrapping them with a polymer [40].
It was proposed [41] that BN polymers, having the structures similar to organic polymers, can serve as a cheap alternative to inorganic semiconductors in designing modern electronic devices. Some related potential innovations, including band gap tuning, were also demonstrated.

The observed giant Stark effect significantly reduces the band gap of BN nanotubes and thus greatly enhances their utility for nanoscale electronic, electromechanical, and optoelectronic applications [42]. In particular, this effect may be important for tuning the band gap of BN nanotubes for applications as a nanoscale field-effect-transistor (FET).

Boron nitride nanotubes have also manifested stable currents in field emission geometry and may be more stable than carbon nanotubes at high temperatures [43,44].

As it was mentioned, boron nitride nanotubes exhibit many similarities with the carbon ones (such as high Young modulus etc.) and might have superior unique mechanical, thermal, and electronic properties [45]. In addition, BN nanotubes are characterized by chemical inertness and poor wetting [46].

The factor that distinguishes BN from C is partial heteropolarity of the chemical bonding. For this reason, one more sphere of possible applications of BN nanotubes can be new pyroelectric and piezoelectric materials promising for applications in nanometer-scale sensors and actuators. The 3-fold symmetry of a BN sheet, the III-V analog to graphite, prohibits an electric polarization in its ground state. However, this symmetry is broken when the sheet is wrapped to form a BN tube. It was shown [47] that this leads to an electric polarization along the nanotube axis which is controlled by the quantum-mechanical boundary conditions of its electronic states around the tube circumference. Thus, the macroscopic dipole moment has an intrinsically nonlocal quantum-mechanical origin from the wrapped dimension. Combining first principles, tight-binding methods and analytical theory, the piezoelectricity of heteropolar (in particular, BN) nanotubes was found [48] to depend on their chirality and radius. This effect can be understood starting from the piezoelectric response of an isolated sheet along with a structure specific mapping from the sheet onto the tube surface. It was demonstrated that a linear coupling between the uniaxial and shear deformations occurs for chiral nanotubes, and the piezoelectricity of nanotubes is fundamentally different from its counterpart in a bulk material. First principles calculations of the spontaneous polarization and piezoelectric properties of BN nanotubes have shown [49] that they are excellent piezoelectric systems with response values larger than those of piezoelectric polymers. The intrinsic chiral symmetry of the nanotubes induces an exact cancellation of the total spontaneous polarization in ideal, isolated nanotubes of arbitrary indexes. But the breaking of this symmetry by the intertube interaction or elastic deformations induces spontaneous polarization comparable to that of wurtzite bulk semiconductors [50].

Multielement nanotubes comprising multiple SiC-core, an amorphous SiO₂-intermediate layer, and outer shells made of BN and C layers separated in the radial direction with diameters of a few tens of nm and lengths up to 50 μm were synthesized by means of reactive laser ablation [51]. They resemble a coaxial nanocable with a semiconductor-insulator-semiconductor (SIS) geometry and suggest applications in nanoscale electronic devices that take advantage of this self-organization mechanism for multielement nanotube formation.

A theoretical description of electron irradiation of single-walled BN nanotubes was presented in [52]. As a first step, the anisotropy of the atomic emission energy threshold was obtained within extended molecular-dynamical (MD) simulations based on the density-functional-theory (DFT) tight-binding method. As a second step, total cross section for different emission sites as a function of the incident electron energy was numerically derived. Two regimes were then described: at low irradiation energies (below 300 keV), atoms are ejected mostly from the upper and lower parts of the tube while at high energies (above 300 keV) atoms are ejected mostly from the side walls. Typical values of the total cross section of knock-on processes are obtained to vary from a fraction of barn (at side wall for 150 keV electrons) up to around 20 barns (for 1 MeV electrons). In BN nanotubes, the emission energy threshold maps were reported to show B sputtering to be more favorable for low irradiation energies, while N sputtering is more favorable at high energies. These calculations of the total knock-on cross section for nanotubes can be used as a guideline for TEM experimentalists using high energy focused beams to shape nanotubes, and also, more generally, if electron irradiation is used to change nanotube properties such as their optical behavior or conductivity.

Such wide field of possible technical and technological applications of boron nitride nanotubes makes useful theoretical research determining their main physical characteristics. In particular, for purposeful design of some materials and devices based on nanotubular BN, like the fibrous composites, tubular heterojunctions, other nanoelectronic devices, nanoreservoirs for hydrogen storage etc., it is very important to be able to predict reliably values of the ground-state parameters, especially, the molar binding energies and sizes of the nanotubes with given indexes and their relative stability. In present work, this task is solved for the most stable – achiral (zigzag and armchair) – single-walled forms.
Paper is organized as follows. In Section 1, we have introduced methods of synthesis of the boron nitride nanotubes and their technological applications. Section 2 is a brief summary of the structural and binding data available on nanotubular boron nitride. In Section 3, the theoretical approach based on the quasi-classical approximation to the binding energy calculation and geometries is presented. In Section 4, results of the performed calculations are presented in the form of curves “molar binding energy – structural parameter”. Section 5 is devoted to estimation of the nanotube lattice zero-point vibration energy. And finally, Section 6 discusses relative stability of the boron nitride nanotubes of various radii and makes an attempt to generalize the obtained results.

2. Structural and Binding Data

Let us start with a brief overview of the structural and binding data available on a boron nitride diatomic molecule, isolated sheet, and nanotubular form.

2.1. Molecular Boron Nitride

The diatomic molecule BN can be considered as a simplest (degenerated) form for boron nitride nanotubes. In general, electronic theory of substance considers a diatomic molecule as a special problem for its intermediate structural and, consequently, electronic properties between mono- and polyatomic systems. Peculiarities are related mainly with the system axial symmetry and uniqueness of the structural parameter – interatomic distance \( d \). Unlike the solid state or nanoscale boron nitrides, which are materials with a diversity of technical and industrial applications, BN molecule, which exists under the extreme conditions, is only of academic interest as a “building block” for two- and three-dimensional boron nitride structures. From the standard thermochemical data, the energy of B–N bond at the equilibrium length is known to be considerably higher compared with those of B–B and N–N bonds. In addition, any stable regular BN structure is a network of atomic rings with alternating atoms such that the nearest-neighbor environment of both B and N atoms consists of only B–N bonds. Therefore, the B–N bond length is a key interatomic distance in the analysis of boron-nitrogen binding.

There are known some old first principles and semiempirical investigations for boron–nitrogen interaction (see [53,54]). Applying a self-consistent-field (SCF) procedure to the BN molecule in [55], it was calculated molecular orbitals (MOs) in order to minimize total energy of the diatomic system. Then using the spectroscopic data available for the corresponding ground state, the BN molecule dissociation energy value \( E \) was found to be 4.6 eV. According to the original theoretical approach of [56], the equilibrium interatomic distance in this molecule equals to 1.307 Å. At the same time, spectroscopic parameters characterizing the calculated boron–nitrogen interaction potential curve lead to the dissociation energy estimation of 5.05 eV. Nearly the same theoretical value for the bond length of 1.320 Å was suggested in [57]. In [58], a short-ranged classical-force-field (CFF) modeling of BN modifications was performed on the basis of experimental and first principles solid-state and diatomic-molecular data. In particular, assuming that CFF can be correctly determined by a sum of only two-body interaction terms, the B–N potential energy had been expressed analytically via Morse potential, which gave \( d \approx 1.32521 \) Å and \( E \approx 5.0007 \) eV. However, it was noted [25] that standard forms of the pair interatomic potentials, such as the Morse, Mee–Grüneisen, Buckingham, and other potentials, converge slowly and, therefore, a cutoff procedure should be used. But, in such a case a non-physical jump on the potential radial function can arise. In order to eliminate this problem, based on the embedded atom method, a new B–N interatomic potential was designed which fulfills the conditions for smooth end: the potential function and its derivative (i.e., the interatomic force) vanish at the cutoff radius. The equilibrium bond length of 1.4457 Å and binding energy of 4.00 eV were found to reproduce correctly relative stabilities of the boron nitride layered structures.

We also suggested [59] a theoretical, namely, quasi-classical method of calculation of the dependence the B–N interatomic binding energy \( E \) upon the bond length \( d \). The constructed \( E = E(d) \) curve was shown to be useful for estimations of BN crystalline structures cohesion parameters as well. This function reveals standard behavior characteristic for the central pair potentials. \( E(0) = -\infty \), and \( E(d) \equiv 0 \) if \( d \) is equal or greater than the sum of B and N quasi-classical atomic radii \( r_{B} \approx 2.30 \) Å and \( r_{N} \approx 1.70 \) Å, i.e., \( d \geq r_{B} + r_{N} \approx 4.00 \) Å (note that quasi-classical B–N interatomic potential automatically fulfills the conditions for the smooth end at \( d = r_{B} + r_{N} \), while within the intermediate region \( 0 < d < r_{B} + r_{N} \) it is an oscillating function with several maxima. Among these maxima only one is available kinetically and, therefore, it corresponds to the equilibrium. Analysis of the piece of the quasi-classical \( E = E(d) \) curve for BN diatomic molecule, in the vicinity of this maximum, yields the values of bond length of 1.55 Å and binding energy of 4.51 eV. Same dependence determined earlier [60,61] within the frames of another quasi-classical parameterization scheme (for this purpose the screening factor of the potential affecting the given electron in interacting atom was approximated by the
radial polynomial, not by the constant) is relatively flat and leads to the estimations of 1.58 Å and 4.79 eV.

Thus, the spread in theoretical and semiempirical values for BN molecule binding energy is (4.0-5.5) eV, which overlaps with the recommended [62] experimental dissociation energy value of (4.0 ± 0.5) eV. The available first principles and semiempirical calculations and thermochemical experimental data lead to the binding energy values of about (4.7) eV per B–N bond for various, differently coordinated, BN modifications (for sheet and nanotubular structures see below). Such kind of estimations may be considered to be in qualitative agreement with the quasi-classically calculated B–N bond energy as the ground state energetic parameters are quite sensitive to the atomic coordination. For this reason, we focus our attention on the differences in the bond length values between BN molecular and crystalline phases.

The quasi-classical values for the isolated B–N bond length and other relevant theoretical and semiempirical data, which lie over the range (1.307-1.580) Å, are overestimated in comparison with 1.281 Å measured in $^{13}$B$^{14}$N molecule [63]. An explanation may be that BN molecular spectra [64] verify triplet ground state, but at the same time reveal a low-lying singlet state with longer bond.

Quasi-classically calculated interatomic vibration energy in a B–N diatomic system of 0.178 eV/mole (the corresponding vibration quantum equals to 1435 cm$^{-1}$) was found by fitting the quasi-classical B–N potential curve with parabola [60,65]. This value is in good agreement (accurate within 5 %) with the values experimentally obtained for a neutral BN molecule of 0.187 (1514.6) [63] and 0.188 eV/mole ((1519.0 ± 0.2) cm$^{-1}$, from the absorption spectra Fourier analysis for laser-induced molecular fluorescence) [64].

According to the SCF theoretical method of [56], the ground state vibration energy in molecular BN estimated as 0.179 eV/mole (1446 cm$^{-1}$), which is almost the quasi-classical result.

In [57], it was suggested the higher theoretical value of 0.217 (1750), what is close with 0.216 eV/mole (1740 cm$^{-1}$) measured in ionized molecule BN$^+$ [66].

Studies of more complex molecular clusters of B and N are also interesting to get deeper insight into the defect formation processes in boron nitride nanotubes. High-temperature Knudsen cell mass spectrometry was used to study the equilibria involving the B$_2$N molecule [67]. The thermal functions necessary to evaluate the mass spectrometric equilibrium data had been calculated from available experimental and theoretical molecular parameters. In particular, in some B$_2$N formation reactions changes in enthalpy have been measured. Room temperature atomization and formation enthalpies were determined to be 10.84 and 5.71 eV, respectively. At the same time, first-principles calculations were performed to estimate the electronic parameters of B$_2$N, such as ionization energy and electron affinity.

Mixed clusters of B and N atoms – B$_2$N, B$_3$N, B$_4$N, B$_5$N, B$_6$N$_2$, and B$_7$N$_2$ – can be produced by sputtering of a solid state BN [68]. Atom ordering in assumed linear species had been derived from measurements of the mass distribution of both the positive and the negative products from the fragmentation of the anionic clusters in a gas target. As for neutral configurations, they were calculated. A tendency was found that a structure with the highest number of B–N bonds is most stable both in neutral and anionic species (an exception is the BN$_2$ molecule). In contrast to this, the species with the highest number of adjacent same atoms (except for triatomic chains) had the largest electron affinity.

2.2. Boron Nitride Sheet

The facts that boron nitride layered crystals and nanotubes may be prepared suggest the necessity of analyzing the hypothetic isolated infinite hexagonal layer, i.e., the BN sheet. Corresponding two-dimensional BN crystal is represented as a planar layer composed of regular hexagons with vertexes alternately occupied by B and N atoms. Classification and discussion of the BN haekelite sheet structures, consisting of not only hexagonal atomic rings but also other even-membered rings, one can find in [69].

For the first time, the truncated crystal approach in the form of two semiempirical (standard and extended iterative Hückel) methods was applied to a two-dimensional hexagonal boron nitride structure [70]. The bond length was found to be 1.48 or 1.50 Å. However, when semiempirical calculations were performed on a two-dimensional periodic small cluster of the h-BN layer the equilibrium B–N distance was computed as 1.441 Å [71]. In [72], the 3-coordinated B$_{12}$N$_{12}$ network of 6-membered atomic rings was examined theoretically. Namely, the total energy calculated using Hartree–Fock (HF) approach and DFT in local and gradient-corrected forms was minimized with respect to the B–N bond length. But, “graphitic” isomer B$_{12}$N$_{12}$ is only a fragment of the BN sheet and its geometry appears to be somewhat distorted because of finite sizes. As is to be expected, slight deviations of the bonds’ angles from the ideal value of 120° were observed for the bonds of atoms forming the central hexagon: $\sim$(2.52-2.65) for B atoms and $\sim$(2.52-2.65) for N atoms. There were also obtained number of unequal bond lengths: (1.266-1.283), (1.371-1.378), (1.427-1.442), (1.434-1.444), (1.520-1.536), and (1.553-1.576) Å. The finiteness of the quasi-classical atomic radii allowed us to obtain the B–N bond length for an infinite boron nitride sheet within the initial quasi-classical approxima-
tion [73]. The calculated dependence of the molar binding energy on the lattice constant exhibits a maximum of 23.0 eV at 2.64 Å, which should correspond to the equilibrium state for an isolated hexagonal layer (analytical optimization [74]) of the lattice parameter using the binding energy calculated in quasi-classical approximation, which is possible only by neglecting the vibration energy, yields slightly different values: 23.2 eV and 2.66 Å, respectively. The lattice constant of 2.64 Å implies B–N bond length of 1.52 Å. Correction in energy introduced by zero-point vibrations was estimated as 0.242 eV/mole [65,73].

The quasi-classical bond length of 1.52 Å in an isolated BN sheet is in reasonable agreement (accurate within 4.6 %) with the bond length of 1.45 Å observed in layers of real h-BN crystals. At first glance, the surprising thing is that the theoretical result for the isolated layer is in better agreement (with the accuracy of (2.6-3.8) %) with the bond lengths in tetrahedrally coordinated modifications c-BN (1.57 Å) and w-BN (1.56 and 1.58 Å). However, it is worth noting that to a certain extent two-dimensional boron nitride looks like three-dimensional crystals c-BN and w-BN: these three structures do not contain weak interlayer bonds, which occur in the h-BN layered modification. The lengths of (1.52-1.54) and (1.55-1.58) Å obtained in [72] for the bonds of atoms forming the central (almost undistorted) hexagon in B_{12}N_{12} plane-fragment are also in good agreement with the quasi-classical result found for an idealized infinite BN sheet. Another quasi-classical approach using a different scheme of parameterization, employed to calculate h-BN binding and zero-point vibration energies, slightly underestimates the intralayer bond length [75]. The plausible reason may be that the crystalline equilibrium configuration was selected to maximize its static binding energy with respect only to the layer lattice parameter, while the interlayer distance was fixed.

Summarizing other theoretical and semiempirical results concerning intralayer bond lengths in h-BN (and r-BN), one can state that all of them are in agreement with the experimental value of 1.446 Å [76]. For instance, in [77] the total energy of h-BN crystal as a function of unit cell volume \( V \) had been calculated using orthogonalized linear-combinations-of-atomic-orbitals (LCAOs) method within the local-density-approximation (LDA). The equilibrium was found at \( V/V_{\text{exp}} \approx 0.998 \), where \( V_{\text{exp}} \) is the experimental value of \( V \). Such result corresponds to the intralayer B–N distance of 1.438 Å. The calculations of [78] were also based on DFT within LDA, but PW expansion was used both for the pseudo-potential (PP) and the wave-function. The computed total energies and, consequently, the intralayer bond lengths in h-BN and r-BN were nearly the same: 1.441 and 1.439 Å, respectively. The short-ranged CFF modeling of boron nitrides leads to exactly the same intralayer B–N bond lengths in both layered structures: 1.454 Å [58]. The results presented show satisfactory accuracy for the quasi-classically determined boron-nitrogen binding characteristics: accuracies of quasi-classical approach to determine isolated B–N bond length and length of bonds in solid state structure amount a few percents, 7.2 and 5.1 %, respectively. Thus, the quasi-classically obtained B–N binding curve and its parameters mentioned above (namely, equilibrium bond length, binding energy, and vibration frequency) would be useful for investigations of compounds containing B–N bonds and, especially, BN nanosystems.

As for the BN sheet binding and vibration energies, it is also reasonable to analyze correctness of the given predictions by comparing them with data available on the cohesion characteristics of h-BN layered crystals. As follows from standard thermochemical data, the binding energy of h-BN equals to 13.0 eV/mole [79]. The binding energies of 14.5, 16.0, and 14.4 eV/mole were determined from semiempirical calculations performed using two variants of the semiempirical LCAOs method and an approach based on a periodic small-sized cluster [70,71]. Within the CFF potential model, the lower semiempirical estimate of 11.5 eV/mole was obtained [58]. In the framework of DFT, optimization of the structural parameters led to the theoretical binding energy of 12.5 eV/mole [78]. Therefore, it can be expected that the molar binding energy for h-BN layered crystal lies in the range from 11.5 to 16.0 eV. The binding energy of 23.0 eV/mole found by the quasi-classical method for the isolated layer is considerably higher. However, when comparing these energies, one should take into account that interlayer bonds are substantially weaker than intralayer ones and that each atom in layered BN structures is involved in the formation of 5 bonds, of which only 3 are intralayer bonds. Consequently, if the interlayer energy is ignored as compared to the intralayer energy, we can assume that the binding energy per B–N bond of similar modifications is equal to 3/5 of the molar binding energy of the isolated layer. Making use of the result 23.0 eV/mole for layer, we find the molar binding energy of 3/5 × 23.0 eV = 13.8 eV. Indeed, this energy is close to the midpoint (13.75 eV) of the aforementioned energy range. On the other hand, the vibration energies of the isolated layer and layered crystals can be directly compared because the atoms of the low-dimensional system can execute vibrations in three independent directions in physical space. The quasi-classical result of 0.242 for two-dimensional BN agrees well with analogous calculations of 0.266 [65], with the semiempirical estimate of 0.225 for zero-point vibrations energy in h-BN [58], and
coincides in order of magnitude with the estimate of 0.350 eV/mole from the theoretical phonon spectrum [78].

A few words about the defects in BN layer. Using PP and expanded unit cell methods, it was found that N-vacancies in BN sheet, as well as di- and trivacancional clusters including neighbor defects in BN layer, are characterized by small binding energies [80]. Calculated spectra and oscillator strengths allow to interpret local bands of the optical absorption in pyrolitic h-BN crystals before and after irradiation by fast-neutrons, protons, and C-ions. By first-principles calculations the 20 structures B\textsubscript{y}C\textsubscript{z}N\textsubscript{r}, derived from a hexagonal layer by placing B, N, or C atoms on each site, were considered [81] to investigate their relative stabilities. First-principles simulations of the interaction of molecular hydrogen H\textsubscript{2} with the native and substitutional defects of a single hexagonal BN sheet were performed in [36]. The adsorption of H\textsubscript{2} on structures found to be endothermic with respect to dissociation. Vacancies reduce the barriers for H\textsubscript{2} dissociation.

The geometries of haeckelite BN sheets were constructed by DFT [82]. Their molar energy of cohesion is found to be higher (by ~0.6 eV/mole) than that of regular one.

2.3. Nanotubular Boron Nitride

The elementary form of a BN nanotube is a wrapped closed hexagonal surface inscribed in the cylinder. Such BN nanotubes can be found in regular – achiral, i.e., zigzag (n,0) or armchair (n,n), and also in chiral (n,m) forms, 0 \leq m \leq n. Here n and m are the tube indexes. Their symmetry operators have been identified in [83]: each type belongs to different family of the non-symmetric rod groups; armchair tubes with even n are found to be centro-symmetric. The types and structures of the non-carbon, in particular, BN nanotubes were reviewed in [84]. In addition, the deformed regular or haeckelite nanotubes can exist. Concerning the haeckelite structures of BN tubes, a variety of chiral angles, including zigzag and armchair types, were observed. Depending on the structure formation kinetics characteristic for a given technology, BN nanotubes quite often take the bamboo-like morphology, form of a nanoarch (i.e., half-tube at the ends closed by planes) etc. Real nanotubular structures are not infinite in length: they are definitely truncated.

The three main different possible morphologies of the cylindrical tube closing with flat [8], conical, and amorphous ends, as observed in experiments, were shown [85] to be directly related to the tube chirality. There are also possible rectangular BN nanotubes with linear defects on edges and with tips in the form of triangular flags. Such kinds of morphologies suggest the presence of energetically unfavorable odd-membered atomic rings (i.e., pentagons and heptagons) in addition to favorable even-membered rings (e.g. squares).

As the growth of BN nanotubes cannot be directly observed and, consequently, the underlying microscopic mechanism is a controversial subject, in [86] first-principles MD simulation of the single-walled nanotube edges was performed. The behavior of growing BN nanotubes was found to strongly depend on the nanotube network chirality. In particular, open-ended zigzag tubes close rapidly into an amorphous tip, preventing further growth. In the case of armchair tubes, formation of squares traps the tip into a flat cap presenting a large central even-membered ring. This structure is meta-stable and is able to revert to a growing hexagonal framework by incorporating incoming atoms. These findings are directly related to frustration effects, namely that B–N bonds are energetically favored over B–B and N–N bonds.

The expressions of radii, \( R_{(n,0)} \) and \( R_{(n,n)} \), of the zigzag and armchair, (n,0) and (n,n), BN nanotubes in terms of the index and the structure parameter \( a \) were obtained [87]. The parameter \( a \) corresponds to the lattice constant of the boron nitride layered crystals, i.e., intra-layer B–B or N–N bonds lengths. Therefore, the B–N bond length \( d \) equals to \( a / \sqrt{3} \). The nanotube index \( n = 1, 2, 3, \ldots \) determines the number of atoms as nanotube unit cell consists of \( 2n \) formula units BN. The estimations of radii of the single-walled BN nanotubes, for their part, can be used for predicting their most probable combinations in multi-walled structures.

Analyzing this problem, it is necessary to take into account that actually the question involves the average radii. A detailed study using the generalized tight-binding MD method has revealed [85] that, as a result of the dynamical relaxation, the structure acquires a wave-like or “rippled” surface in which B atoms are displaced inward, while N atoms are displaced outward. This relaxation is similar to the reconstruction occurring at clean surfaces of III-V type crystalline semiconductors. However a general feature of BN nanotubular systems is that stronger surface potentials are associated with regions of higher curvature [88]. Thus, the interlayer interaction in BN nanotubes differs from bonding in three-dimensional layered crystals. However, most probably, these distinctions for nanotubular BN are weak enough to change essentially the equilibrium interlayer distances which are observed in h-BN and r-BN crystals. This conclusion is also confirmed by the results of an experimental study of the multi-walled nanotubes by high-resolution electronic microscopy [89]. In these structures, like in three-dimensional layered BN crystals, hexagonal and rhombohedral stacking sequences can freely coexist in nanotube wall-assembly. There are also possible some different cross-
section flattening, as well as ordering of layers in non-spiral zigzag. According to first-principles total-energy calculations [90], the most favorable double-walled BN nanotubes are structures in which the inter-wall distances are about 3 Å, i.e., as interlayer distances in layered BN crystals. Therefore, due to the weakness of the interlayer van der Waals forces, various types of multi-walled BN nanotubes can exist. Consequently, it is more probable the formation of such multi-walled BN nanotubes in which the difference between the radii of adjacent regular nanotubes is close to the interlayer distance in a layered h-BN crystal, i.e., to half of the height of the hexagonal unit cell \( c \approx 6.6612 \text{ Å} \) [91]. Thus, the similarity between types of the adjacent nanotubes has no crucial importance.

In view of these factors, from the calculated single-walled nanotubes [87] pairs most suitable for the formation of the stable double-walled BN nanotubes have been chosen. Remaining small divergences in sizes of the neighboring regular nanotubes can be compensated by defects and small chiral distortions. Such transformations of the zigzag and armchair nanotubes into chiral one will be accompanied, respectively, by the increase and decrease in their radii. If the difference in radius between regular nanotubes is more (less) than \( c/2 \), the realization of structure in which the internal wall will be zigzag (armchair) and external – armchair (zigzag) is more probable. Hence, based on estimations of sizes of the single-walled BN nanotubes, it is possible to predict successfully the most stable double-walled forms. But, how can be solved the same problem for multi-walled nanotubes? A few words on the task. In this case, all over, it will be necessary to calculate radii of nanotubes with high indexes to choose sequences of single-walled nanotubes, whose radii are close to terms of arithmetic progression with common difference of \( c/2 \). However, now only geometrical considerations will be insufficient. The point is that unlike double-walled nanotubes in multi-walled ones there are also medial layers. For this reason, the choice of the most stable multi-walled structure should be based on the comparison between the gains in energy, which are caused by the deviation from the equilibrium interlayer distance, on the one hand, and by chiral distortions, on the other hand.

We can mention some theoretical results available on binding properties and stabilities of BN nanotubes. Stabilities of the boron nitride nanotubular structures were studied by means of non-orthogonal tight-binding formalism [92]. The radii and energies of the BN nanotubes also were estimated by MD simulation [25] within the embedded atom model in which parameter \( d \) took the experimental value 1.4457 Å of the intralayer B–N bond length in real h-BN crystals. In [69], the binding energy of the regular BN nanotubes has been calculated within the DFT in generalized gradient approximation (GGA). Seeking equilibrium values of B–N bond length and radii, the geometry of the tubular 32-atom supercell was optimized. For \((8,0)\), \((10,0)\) and \((4,4)\) tubes, it has been found \( d \approx 1.46 \text{ Å} \), and for \((5,5)\) tube, \( d \approx 1.45 \text{ Å} \). Within the frame of semiempirical calculations of the nanotubular piezoelectric characteristics performed by the method of modified neglecting of diatomic overlapping (MNDO) [50], their radii also were determined. In this case the dependence of energies on the bond length was calculated for the molecular fragments containing 3 or 4 elementary layers (presumably, in this work for \( d \) the empirical value known for h-BN crystals was fixed as an equilibrium value).

The possible contribution of ionicity of bonds in boron nitride structures is important to explain the binding differences between BN tubes and similar C tubes [1]. In order to facilitate understanding and prediction of nanotube interactions in a multi-walled structure, the electrostatic potentials on both outer and inner surfaces of some single-walled BN nanotubes have been calculated at a HF Slater-type-orbital level [88]. Structures were optimized computationally. Fictitious hydrogen atoms were introduced at the ends of the open tubes to satisfy the unfulfilled valences. It was found that BN tubes have stronger and more variable surface potentials than graphitic ones. There are characteristic patterns of positive and negative sites on the outer lateral surfaces, while the inner ones are markedly positive.

The binding and vibrations in small-radius single-walled BN nanotubes in [93] were studied by DFT using LDA. The results show that the chirality preference observed in experiments may be explained from the relative stability of the corresponding BN strips: the zigzag strips have larger binding energies and thus may be more easily formed. The smallest stable BN nanotube is found to be the \((5,0)\) zigzag nanotube. The dependence of the tube deformation energy on its radius \( R \) was approximated by the formula \( \Delta E \ [\text{eV/mole}] = 5.82 / R^{2.09} \) [Å]. The phonon dispersions of BN nanotubes were calculated and the frequency of the radial breathing mode was found to be inversely proportional to the nanotube radius. The geometries of the BN nanotubes were also constructed in DFT [82]. Based on DFT calculations [69], it was found that the energies of haeckelite BN nanotubes exceed by \( \sim 0.6 \text{ eV/mole} \) those of corresponding hexagonal nanotubes. They are less stable in comparison with corresponding haeckelite sheets as well. However, still they are stable and can be synthesized. Energy of deformation (i.e., energy needed to wrap nanotube from its sheet prototype) for large haeckelite BN tubes extrapolated by the formula \( \sim C / R^d \), where \( R \) is the tube radius, with different
parameters $C$ and $\alpha = 2$ for different structures.

Using the symmetry properties in [83], it was determined the numbers of Raman- and infrared (IR)-active vibrations in single-walled BN nanotubes. In contrast to the regular carbon nanotubes, zigzag boron nitride tubes possess almost twice as many vibrations as armchair ones. An extensive first principles study of the phonons in BN nanotubes using perturbation DFT in the LDA was performed in [94], where, based on the non-symmetric rod group symmetry of tubes, the Raman- and IR-active modes at the point of the one-dimensional Brillouin zone were evaluated. For zigzag and chiral nanotubes, the set of IR-active modes is a subset of the Raman-active modes. In particular, the radial breathing mode is not only Raman-, but also IR-active. However, for armchair tubes, the sets of IR- and Raman-active modes are disjoint. The frequencies of the active modes of zigzag, chiral, and armchair tubes were presented as a function of the tube diameter. They were compared with the frequencies obtained by the zone-folding method (i.e., by rolling of a BN sheet into a tube). Except for the high-frequency tangential modes, the zone-folding results are in very good agreement with the first principles calculations. The radial breathing mode frequency can be derived by folding a sheet of finite width. Finally, the effects of bundling on the phonon frequencies are shown to be small. First principles calculations of the nonresonant Raman spectra of zigzag and armchair BN nanotubes were presented in [95]. In comparison, a generalized bond-polarizability model, where the parameters are extracted from first principles calculations of the polarizability tensor of a BN sheet, was implemented. For light polarized parallel to the tube axis, the agreement between model and first principles spectra is almost perfect, but for perpendicular polarization, depolarization effects have to be included in the model in order to reproduce Raman intensities.

The possible dislocation dipoles as defect nuclei under tension in BN nanotubes were identified by dislocation theory and MD simulations [96]. Formation energies of the dipoles evaluated by gradient-corrected DFT are high and remain positive at large strains, thus suggesting great yield resistance of BN nanotubes. The dipole appears to be more favorable in spite of its homoelemental B–N bond rotation effect, the compressed zigzag nanotubes were found to undergo anisotropic strain release followed by anisotropic plastic buckling. The strain is preferentially released toward N atoms in the rotated B–N bonds. The tubes buckle anisotropically toward only one end when uniaxially compressed from both ends. Based on these results, a skin-effect-model of smart nanocomposite materials is proposed, which localizes the structural damage toward the surface side of the material. B–N bond-rotation mode of plastic yield in BN nanotubes in [101] was investigated combining first principles computations with a probabilistic rate approach to predict the kinetic and thermodynamic strength. BN nanotubes yield defects have low activation, but high formation energies. In [50], elastic characteristics of BN nanotubes also were calculated applying MNDO method.

3. Theoretical Basis

Our calculations are based on the quasi-classical expression for binding molar energy of a substance, on the one hand, and on the geometric characterization of nanotubular boron nitride, on the other hand.

3.1. Quasi-Classical Binding Energy of Substance

Under the term 'substance' we imply polyatomic structures at the ground state, i.e., molecules, various clusters, and crystals. Consequently, any substance is considered as a non-relativistic electron system affected by the static external field of nuclei, which are fixed at the sites in structure, and the averaged SCF of electrons. Because of singularities at the points, where the nuclei are located, and electron shell effects as well the inner potential of
substance does not satisfy the standard Wentzel–Kramers–Brillouin (WKB) quasi-classical condition of spatial smoothness. Nevertheless, beginning from Bohr’s fundamental work ‘On the constitution of atoms and molecules’ up to the present the semi-classical analysis of the electronic spectrum has been widely used for light atoms and their small complexes. Besides, heavy atoms, large molecules, and crystals can be treated within the LDA using the total energy functional in the form of quasi-classical expansion. Success of quasi-classical approaches can be attributed to the diffuseness of atomic potentials. The expression for bounded electron states energies obtained by Maslov yields that precise and quasi-classical spectra are close to each other if the characteristic values of potential \( \Phi_i \) and the radius of its action \( R_0 \) meet requirement \( 2\Phi_i R_0^2 >> 1 \) (here and below all relations are given in atomic units). For atomic potential \( \Phi_0 \sim Z/R \) and \( R_0 \sim R \) where \( Z \geq 1 \) is the atomic number and \( R \) is the radius of electron cloud. Therefore, in case of atoms it is required that \( 2ZR >> 1 \). Even for light atoms their radii are several times larger than Bohr radius, \( R >> 1 \). Thus atoms and all polyatomic structures indeed are quasi-classical electron systems and their structural and electronic characteristics can be calculated based on the quasi-classically parameterized electric charge density and electrical field potential distributions in atoms.

The values of \( i \)-th electron classical turning point radii \( r_i' \) and \( r_i^* \), \( r_i' < r_i^* \), are obtained by solving the equations

\[
E_i = -\Phi_i(r) + \frac{l(l+1)}{2r^2} \quad i = 1, 2, 3, ..., Z,
\]

where \( r \) denotes the distance from the center of atom, \( \Phi_i(r) \) is the potential affecting the given electron, \( E_i < 0 \) and \( l_i \) are its energy and orbital quantum number, respectively.

In the ground state the inner classical turning point for relative motion of atomic nucleus and electron cloud coincides with the center of system. As for the corresponding outer classical turning point radius \( \tilde{r} \), it is obtained by solving the equation

\[
\tilde{E} = Z\Phi(\tilde{r}),
\]

where \( \tilde{E} < 0 \) denotes the energy associated with relative motion and

\[
\Phi(r) = -\frac{1}{Z - 1} \left( \frac{Z^2}{r} - \sum_{i=1}^{Z} \Phi_i(r) \right)
\]

is the electron cloud potential affecting the nucleus.

In particular, using the quasi-classical parameterization based on the Coulomb-like atomic potentials \( \Phi_i(r) \)

we are able to get exact formulas

\[
r_i' = \frac{n_i - \sqrt{n_i^2 - l_i(l_i+1)}}{Z_i}, \quad r_i^* = \frac{n_i + \sqrt{n_i^2 - l_i(l_i+1)}}{Z_i}, \quad \tilde{r} = \frac{2(Z-1)}{Z^2 - \sum_{i=1}^{Z} Z_i} \left( \sum_{i=1}^{Z} \frac{Z_i^2}{Z^2} \right)^2, \quad \tilde{E} = \frac{Z^2}{2(Z-1)^2}.
\]

Here \( Z_i = n_i \sqrt{-2E_i} \) is the effective charge of the screened nucleus and \( n_i \) is the principal quantum number of \( i \)-th electron. The numerical values of \( Z_i, \tilde{E}, r_i', r_i^* \) and \( \tilde{r} \) can be found by fitting the quasi-classical energy levels \( E_i \) to ab initio (for instance HF) ones.

Quasi-classical limit implies the truncation of electron states charge densities outside the classical turning points and space-averaging within the range between them. In this case \( i \)-th electron partial charge density is approximated by the piecewise-constant radial function

\[
\rho_i(r) = \begin{cases} 0 & r < r_i' \\ \frac{3}{4\pi(r_i^* - r_i'^2)} & r_i' < r < r_i^* \\ 0 & r_i^* < r \end{cases}
\]

As for the nucleus charge density, it should be averaged inside the \( \tilde{r} \)-sphere:

\[
\tilde{\rho}(r) = \frac{3Z}{4\pi \tilde{r}^3} \quad 0 < r < \tilde{r}.
\]

Consequently, the full atomic charge density is expressed by the step-like radial function

\[
\rho(r) = \tilde{\rho}(r) + \sum_{k=1}^{q} \rho_k(r) \equiv \rho_k
\]

\[
r_{k-1} < r < r_k \quad k = 1, 2, 3, ..., q,
\]

where \( r_k \) and \( \rho_k \) denote known constants which depend on parameters \( r_i', r_i^* \) and \( \tilde{r} \), \( 0 = r_0 < r_1 < \cdots < r_q < \infty \), \( q \leq 2Z \) is the number of different homogenous-charge-density spherical layers in atom.

Using the Poisson equation, the radial dependence of the full atomic potential also can be approximated by the
step-like function,
\[ \varphi(r) = \frac{3a_k(r_k^2 - r_{k-1}^2)}{2(r_k^3 - r_{k-1}^3)} + \frac{3b_k(r_k^3 - r_{k-1}^3)}{5(r_k^3 - r_{k-1}^3)} + c_k = \varphi_k \]
where \( r_{k-1} < r < r_k \), \( k = 1, 2, 3, \ldots, q \),
\[ a_k = \sum_{i=1}^{i=q} 4\pi \rho_i(r_i^3 - r_{i-1}^3)/(3) \quad b_k = \frac{2\pi \rho_k}{3} \]
and \( c_k = \sum_{i=k+1}^{i=q} 2\pi \rho_i(r_i^3 - r_{i-1}^3) + 2\pi \rho_k r_k^3 \)
if it is substituted by the space-averaged values inside each of the \( r_{k-1} < r < r_k \) intervals.

In the region \( r > r_k \), both the charge density and potential vanish identically, \( \rho(r) = 0 \) and \( \varphi(r) = 0 \). Thus finite parameter \( r_k \) acquires a meaning of the quasi-classical atomic radius.

Based on the presented step-like parameterization of the charge density and potential distributions in an atom, its quasi-classical total energy can be expressed in the following form:
\[ E_{\text{atom}} = \frac{\pi}{3} \sum_{k=1}^{q} \rho_k \varphi_k (r_k^3 - r_{k-1}^3) < 0 . \]

Note that it includes the non-physical energy of self-action, \( E_{\text{atom-self-action}} > 0 \) which arises from substituting the charge density for the probability density. Its value can be easily calculated in the quasi-classical approximation and then excluded from the total energy.

When the molecular or crystalline charge densities and potentials are expressed by the superposition of the step-like atomic charge densities and potentials, respectively, the molar (i.e., per chemical formula unit of the substance) ground state static energy and its zero-point vibration correction are calculated as
\[ E_{\text{static}} = \frac{1}{4} \sum_{i=1}^{i=N} \sum_{j=1}^{j=N} \sum_{l=1}^{l=N} \rho_{ijl} \varphi_{ijl} V_{ijl}(r_{ijl}) < 0 , \]
where \( N \) is the number of atoms, \( M_{i} \) is the mass of \( i \)-th atom, \( \bar{r} \) is the crystal translational vector – in case of a molecule \( \bar{r} = 0 \), \( r_{ijl} \) is a distance between atomic sites and \( V_{ijl} \) is the potential energy function.

We have introduced an universal geometric function \( V(R_1, R_2, D_{12}) \) which expresses the volume of the intersection of two spheres as a function of their radii \( R_1 \) and \( R_2 \), and the inter-center distance \( D_{12} \): \( V(R_1, R_2, D_{12}) = \frac{4\pi R_1^3}{3} \) \( D_{12} \leq R_1 - R_2 \),
\[ = \frac{4\pi R_1^3}{3} \quad D_{12} \leq R_1 - R_2 , \]
\[ = \pi(R_1 + R_2 - D_{12})^2((R_1 + R_2 + D_{12})^2 - 4(R_1^2 - R_2 R_2 + D_{12}^2)) \]
\[ = 0 \quad R_1 + R_2 \leq D_{12} ; \]
\[ \frac{\partial V}{\partial D_{12}} = 0 \quad D_{12} \leq R_1 - R_2 , \]
\[ = -\pi((R_1 + R_2)^2 - D_{12}^2)(D_{12}^2 - (R_1 - R_2)^2) \]
\[ = 0 \quad R_1 + R_2 \leq D_{12} . \]

In the lowest quasi-classical approximation, the equilibrium structure of substance is obtained by maximizing the molar binding energy of expected structures.
with respect to their structural parameters.

However, neglecting the insignificant redistribution of valence electrons arisen from association of atoms into a molecular or crystalline structure, the quasi-classical self-action energy of the substance is approximated by the sum of self-action energies of constituent atoms:

\[ E_{\text{Self-Action}} \approx \sum_{i=1}^{N} E_{(i)\text{Self-Action}}. \]

And consequently, the binding energy approximately can be calculated without excluding of the self-action terms in advance:

\[ E_{\text{Binding}} \approx \sum_{i=1}^{N} E_{(i)} - E_{\text{Static}} - E_{\text{Fibration}} > 0. \]

The expected errors of the quasi-classical approach can be estimated for the model inner potential in the form of the analytical solution of the Thomas–Fermi (TF) equation for the semi-classical atomic potential: structural and energy parameters of the electronic system determined within the initial quasi-classical approximation are shown to differ from their exact values by factors min\(\text{ed within the initial quasi-classical approximation are no uncontrollable calculation errors due the finiteness of quasi-classical atomic radii – the pair interactions without series termination are truncated at the distances exceeded the sums of atomic radii.}

A complete quasi-classical theory of substance including calculation schemes for structural and binding, as well as for electronic spectrum characteristics, one can find in [102,103]. These schemes have been applied successfully for Na molecular and crystalline structures [104], various diatomic molecules [60,61], boron nanotubes [105,106], and mainly for one-, two- and three-dimensional structural modifications of boron nitride – diatomic molecule, isolated plane sheet, hexagonal h-BN, cubic c-BN, and wurtzite-like w-BN crystals [59,60,64,73-75,107,108].

### 3.2. Geometries of the Boron Nitride Regular Single-Walled Nanotubes

Summarizing previous subsection, one can conclude that equilibrium structural and binding parameters of the boron nitride nanotubes can be calculated quasi-classically based on analytical expressions describing their geometries. This task has been solved in [87,108,109] for regular (achiral), i.e., zigzag \((n,0)\) and armchair \((n,n)\) BN nanotubes. A model of regular nanotubes used here assumes that all atomic sites are located on cylindrical surface at the vertexes of regular hexagons broken along B–N or B–B and N–N diagonals, i.e., the expected small differences in bond length distinguished by their orientation toward the tube axis are neglected.

Namely, radii \(R_{(n,0)}\) and \(R_{(n,n)}\) of the zigzag and armchair nanotubes have been obtained \([87,108]\) in terms of the nanotube index \(n = 1,2,3,...\) and the structure parameter \(a:\)

\[ R_{(n,0)} = \frac{a}{4\sin \pi/2n}, \]

\[ R_{(n,n)} = \frac{\sqrt{5} + 4 \cos \pi/2n a}{4\sqrt{3} \sin \pi/2n}. \]

As it was mentioned, the parameter \(a\) corresponds to a lattice constant of the boron nitride layered crystals, i.e., to an intralayer B–B or N–N bond lengths. Therefore, the B–N bond length \(d\) equals to \(a/\sqrt{3}\). The nanotube index \(n\) determines the number of atoms, as a nanotube unit cell consists of \(2n\) formula units, \(\text{B}_2\text{N}_{2n}\).

Detailed regular geometries of zigzag and armchair BN nanotubes have been described in [108,109] using cylindrical coordinates \((\rho, \varphi, z)\), which are useful for calculating binding energy.

A unit cell of zigzag nanotubes consists of 4 atomic rings in parallel planes perpendicular to the axis. There are 2 pairs of rings, each consisting of 2 planes with \(n\) boron or \(n\) nitrogen atoms. Obviously, the cylindrical coordinate \(\rho\) for all atomic sites equals to the tube radius:

\[ \rho_B = \rho_N = R_{(n,0)}. \]

As for the coordinates \(\varphi\) and \(z\) in the first and second pairs of atomic rings, they equal to

\[ \varphi_B = \varphi_N = 2\pi / n, \]

\[ z_B = (6m+1)a/2\sqrt{3}, \]

\[ z_N = (6m-1)a/2\sqrt{3}, \]

and

\[ \varphi_B = \varphi_N = (2l+1)\pi / n, \]

\[ z_B = (3m+1)a/\sqrt{3}, \]

\[ z_N = (3m-1)a/\sqrt{3}, \]

depending on \(l = 0,1,2,...,n-1\) and \(m = 0,\pm1,\pm2,...\) number atomic pairs in a given pair of the atomic rings and these rings themselves, respectively.

The unit cell of armchair nanotubes consists of 2 atomic rings in parallel planes perpendicular to the tube axis. For its part, each ring consists of \(n\) boron and \(n\) nitrogen atoms. The coordinate \(\rho\) for all atomic sites again equals to the tube radius:

\[ \rho_B = \rho_N = R_{(n,n)}. \]
while the rest cylindrical coordinates in the first and second atomic rings equal to
\[ \phi_b = \frac{2l\pi}{n}, \]
\[ \phi_n = -\phi_b + \frac{2l\pi}{n}, \]
\[ z_b = z_N = ma, \]
and
\[ \phi_b = -\phi_1 - 2\phi_2 + \frac{2l\pi}{n}, \]
\[ \phi_n = \phi_1 + 2\phi_2 + \frac{2l\pi}{n}, \]
\[ z_b = z_N = (2m+1)a/2, \]
respectively. Here
\[ \sin \phi_1 = \frac{2\sin \pi/2n}{\sqrt{5+4\cos \pi/2n}}, \]
\[ \sin \phi_2 = \frac{4\sin \pi/2n}{\sqrt{5+4\cos \pi/2n}}, \]
and \( l = 0, 1, 2, ..., n-1 \) and \( m = 0, 1, 2, ..., \) number B or N atoms in atomic rings and these rings themselves.

Based on the above discussion, the distances between a given atomic site and the sites in the so-called central atomic pairs (with \( l = m = 0 \)) in zigzag and armchair nanotubes have been found.

For zigzag \( (l = m = 0) \), \( \phi_b = \phi_0 = 0 \), \( z_b = a/2\sqrt{3} \), and \( z_N = -a/2\sqrt{3} \) tubes
\[ \frac{(l_{(n,0)}B1 - \theta_{(n,0)}B1)}{a^2} = \sin^2 \frac{l\pi}{n} + 3m^2, \]
\[ \frac{(l_{(n,0)}B2 - \theta_{(n,0)}B1)}{a^2} = \sin^2 \frac{(2l+1)\pi}{2n} + 3(2m-1)^2, \]
\[ \frac{(l_{(n,0)}N1 - \theta_{(n,0)}B1)}{a^2} = \sin^2 \frac{l\pi}{2n} + 4, \]
\[ \frac{(l_{(n,0)}N2 - \theta_{(n,0)}B1)}{a^2} = \sin^2 \frac{3(2m-1)^2}{4 \sin^2 \frac{l\pi}{2n}} + 3m^2, \]
\[ \frac{(l_{(n,0)}B1 - \theta_{(n,0)}N1)}{a^2} = \sin^2 \frac{l\pi}{n} + 3m^2, \]
\[ \frac{(l_{(n,0)}B2 - \theta_{(n,0)}N1)}{a^2} = \sin^2 \frac{l\pi}{2n} + 3m^2, \]
\[ \frac{(l_{(n,0)}N1 - \theta_{(n,0)}N1)}{a^2} = \sin^2 \frac{2l\pi}{2n} + 3(2m-1)^2, \]
\[ \frac{(l_{(n,0)}N2 - \theta_{(n,0)}N1)}{a^2} = \sin^2 \frac{(2l+1)\pi}{2n} + 3m^2, \]
\[ \frac{(l_{(n,0)}B1 - \theta_{(n,0)}B1)}{a^2} = \sin^2 \frac{l\pi}{n} + 3(2m+1)^2, \]

4. Binding Energies in Dependence on Structural Parameter

At first, based on the above stated relations and HF values of the atomic electron energy-levels tabulated in [110], the required quasi-classical parameters \( \delta_b \), \( \rho_b \), and \( \phi_b \) for constituent atoms B and N have been calculated. They are given in Tables 1 and 2, respectively.

Here the values are shown in atomic units with 7 significant digits in accordance with the accuracy of input data (HF energies). Such high accuracy is useful in interm calculations. As for the final results, they should be expressed in rounded figures with 3 or 4 significant digits (in Å or eV for structure or energy parameters, respectively) because it corresponds to the usual experimental errors when determining structure and energy parameters of a substance, and the relative errors of the semi-classical calculations aimed at finding theoretically these parameters for polyatomic systems amount to a few percents.
Table 1. Quasi-classical parameters of step-like radial distributions of electron-charge-density and electric-field-potential in boron atom (in a.u.).

<table>
<thead>
<tr>
<th>k</th>
<th>1</th>
<th>2</th>
<th>3</th>
<th>4</th>
<th>5</th>
</tr>
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<tbody>
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<td>$r_i$</td>
<td>2.758476E−02</td>
<td>5.098016E−01</td>
<td>7.441219E−01</td>
<td>4.021346E+00</td>
<td>4.337060E+00</td>
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<tr>
<td>$\rho_i$</td>
<td>5.686514E+04</td>
<td>−3.610951E+00</td>
<td>−7.342212E−03</td>
<td>−1.028341E−02</td>
<td>−2.941197E−03</td>
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<tr>
<td>$\phi_i$</td>
<td>2.105468E+02</td>
<td>8.882329E+00</td>
<td>3.652920E+00</td>
<td>2.060720E−01</td>
<td>6.135348E−04</td>
</tr>
</tbody>
</table>

Table 2. Quasi-classical parameters of step-like radial distributions of electron-charge-density and electric-field-potential in nitrogen atom (in a.u.).

<table>
<thead>
<tr>
<th>k</th>
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<th>2</th>
<th>3</th>
<th>4</th>
<th>5</th>
</tr>
</thead>
<tbody>
<tr>
<td>$r_i$</td>
<td>9.446222E−03</td>
<td>3.577244E−01</td>
<td>5.498034E−01</td>
<td>2.909074E+00</td>
<td>3.204489E+00</td>
</tr>
<tr>
<td>$\rho_i$</td>
<td>1.982589E+06</td>
<td>−1.044967E+01</td>
<td>−1.939444E−02</td>
<td>−4.126981E−02</td>
<td>−2.187537E−02</td>
</tr>
<tr>
<td>$\phi_i$</td>
<td>8.784581E+02</td>
<td>2.022523E+01</td>
<td>8.464698E+00</td>
<td>5.096684E−01</td>
<td>3.993358E−03</td>
</tr>
</tbody>
</table>

Using these parameters and expressions for the components of the quasi-classical molar binding energy and squared interatomic distances in zigzag and armchair BN nanotubes (Figures 1 and 2), their binding energies were calculated versus the structural parameter $a$ with spacing of 0.001 a.u., i.e., within the accuracy of 4 significant digits. The vibration energy is assumed to be zero when the radicand in its formula becomes negative.

In order to carry out these massive calculations, a special computer code has been designed. Calculations were performed within the range of the structure parameter $a$ which varied from 1 to 13 a.u. with a step $\Delta a = 0.001$ a.u. (that is quite enough to cover values having any physical sense). The nanotube indexes varied from $n = 1$, covering zigzag and armchair nanotubes up to (18,0) and (10,10), respectively. The radii of the largest calculated species are approximately equal. They are sufficiently large for the tube molar binding energy to almost reach the “saturation” value, which is given by the binding energy of the planar hexagonal BN sheet. In order to make sure that such “saturation” indeed takes place, test species with very large indexes (45,0) and (26,26) (again with approximately equal radii) have also been calculated.

Figures 3-6 show $E_{\text{Binding}}(a)$ curves (and their trends near the peaks) for some zigzag and armchair BN nanotubes, respectively. One can see that at sufficiently small interatomic distances binding energy might take a large negative value that implies that the structure is unstable, while at sufficiently large interatomic distances the binding energy always equals to zero which reveals atomization of a structure. As for the intermediate distances, the molar binding energy is positive that is a signature of structural stability. In this case, general trend in binding energy value is decreasing. However, $E_{\text{Binding}}(a)$ curves are not monotonous, but with several extremes. Such kind of oscillatory behavior of the molar binding energy of

\[ E_{\text{Binding}}(a) \]

Figure 1. Structure of a zigzag BN nanotube.

Figure 2. Structure of an armchair BN nanotube.
any atomic structure against the inter-atomic distances reflects electron-shell-structure of the constituent atoms (note that the interaction between particles of matter with forces non-monotonously decreasing with distance was foreseen as early as in 18th century by Boscovich [111], whose atomic theory was based only on abstract philosophical speculations).

Figures 7 and 8 show the binding energies for the two types of achiral nanotubes with the same index $n$ (namely $(3,0)$ and $(3,3)$ nanotubes).

Let us discuss which of the peaks in these figures correspond to the equilibrium structure. The first peak from the right is lower than the successive one. This second peak for all tubes located at $a = 5.085$ a.u. (2.691 Å) seems to correspond to the realized stable BN nanotubular structures (the detailed behavior of $E_{\text{Binding}}(a)$ curves in its vicinity is shown in Figures 4, 6 and 8). The next peak, even being higher than this, can not been reached kinetically in standard laboratory conditions because they correspond to lower interatomic distances and these two peaks are separated by very deep and sufficiently wide minima, i.e., by high and wide potential barriers which can be overcome only at ultrahigh temperatures or tunneled only at ultrahigh pressures.

The obtained equilibrium binding energies of BN nanotubes of both achiral types are summarized in Table 3.
Molar Binding Energy of Zigzag and Armchair Single-Walled Boron Nitride Nanotubes

Figure 6. Molar binding energies of armchair BN nanotubes with different indexes \( n \) near the peak \( a = 2.691 \, \text{Å} \).

Figure 7. Dependence of molar binding energies of zigzag and armchair BN nanotubes with the nanotube index \( n = 3 \) on the structural parameter \( a \).

together with their radii calculated from formulas for equilibrium value of the structural parameter \( a = 2.691 \, \text{Å} \).

Thus, the molar binding energies of small-sized nanotubes, both zigzag and armchair have peaks at (3,0) and (2,2), respectively. Then for large indexes the binding energies decrease toward the same constant value (see Figures 9 and 10).

Figure 11 presents the dependence of the molar binding energy of achiral BN nanotubes on their radii \( R \). It reveals pairs of minima at (1,0) and (2,0), and maxima at (1,1) and (3,0), i.e., all the extremes are located in low-radii-region. At higher radii, the molar binding energy slowly decreases to the value of 23.26 eV, which, apparently, corresponds to that of the plane hexagonal BN sheet.

The obtained dependence \( E_{\text{Binding}}(a) \) in its domain of monotonicity seems to be quite smooth. It allows us to extrapolate this curve also to chiral BN nanotubes (Figure 12) because the radius of a chiral tube \( R_{(n,m)} \) together with their indexes \( n \) and \( m \) meet the condition \( 0 \leq m \leq n \) and radii of the corresponding achiral tubes always meet the condition \( R_{(n,0)} \leq R_{(n,m)} \leq R_{(n,n)} \).

The results of the carried out calculations are pre-
Table 3. Quasi-classically calculated radii and binding energies of BN nanotubes.

<table>
<thead>
<tr>
<th>Nanotube</th>
<th>Radius, Å</th>
<th>Binding Energy, eV/mole</th>
</tr>
</thead>
<tbody>
<tr>
<td>(1,0)</td>
<td>0.673</td>
<td>12.26</td>
</tr>
<tr>
<td>(1,1)</td>
<td>0.868</td>
<td>26.08</td>
</tr>
<tr>
<td>(2,0)</td>
<td>0.951</td>
<td>23.17</td>
</tr>
<tr>
<td>(3,0)</td>
<td>1.345</td>
<td>29.72</td>
</tr>
<tr>
<td>(2,2)</td>
<td>1.537</td>
<td>27.59</td>
</tr>
<tr>
<td>(4,0)</td>
<td>1.758</td>
<td>26.40</td>
</tr>
<tr>
<td>(5,0)</td>
<td>2.177</td>
<td>24.74</td>
</tr>
<tr>
<td>(3,3)</td>
<td>2.260</td>
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<tr>
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<td>23.92</td>
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<td>3.729</td>
<td>23.68</td>
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<tr>
<td>(9,0)</td>
<td>3.874</td>
<td>23.64</td>
</tr>
<tr>
<td>(10,0)</td>
<td>4.300</td>
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</tr>
<tr>
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<tr>
<td>(45,0)</td>
<td>19.276</td>
<td>23.26</td>
</tr>
<tr>
<td>(26,26)</td>
<td>19.290</td>
<td>23.26</td>
</tr>
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</table>

Figure 11. Molar binding energy of achiral BN nanotubes vs the nanotube radius $R$.

Figure 12. Structure of a chiral BN nanotube.

On the one hand, within the above formulated quasi-classical approach, all binding energy maxima are related with the onset of overlapping between certain regions of homogeneity of electric charge density and electric field potential in interacting atoms, constituents of the structure under the consideration. Namely, equilibrium point at $a \approx 5.085$ a.u. corresponds to the B–N bond length of $d \approx 2.937$ a.u. which is a sum of radii B $r_B \approx 0.028$ a.u. and N $r_N \approx 2.909$ a.u. (Tables 1 and 2).

On the other hand, quasi-classical expression of the vibration energy is based on the parabolic approximation of the $E_{\text{Binding}}(a)$ curve and formula for the volume of the intersection of two spheres, $V(R_1, R_2, D)$, which is a continuously differentiable function of the inter-central distance $D$. However, one can see readily from expression of its first (continuous) derivative that second derivative is not a continuous function.

That is the reason why the parabolic approximation of the $E_{\text{Binding}}(a)$ curve in the immediate vicinity of the...
Molar Binding Energy of Zigzag and Armchair Single-Walled Boron Nitride Nanotubes

Figure 13. Surface plot of the molar binding energy \( E_{\text{Binding}}(a,n) \) of a zigzag BN nanotube as a function of the structural parameter \( a \) and nanotube index \( n \).

Figure 14. Surface plot of the molar binding energy \( E_{\text{Binding}}(a,n) \) of an armchair BN nanotube as a function of the structural parameter \( a \) and nanotube index \( n \).

The dependence of the molar vibration energy on the BN nanotube radius qualitatively reproduces that for the binding energy. However, this dependence is very weak and, thus, the molar vibration energy can be considered as almost independent from the tube radius, \( ~0.3 \) eV/mole.

Of course, the vibration corrections to the binding energy are too weak to change character of the \( E_{\text{Binding}}(R) \) dependence.

6. Concluding Remarks

The quasi-classically calculated structure parameter \( a = 2.691 \) Å of single-walled boron nitride nanotubes is in satisfactory agreement with experimental value for the h-BN layered crystals \( a_{\text{exp}} = 2.504 \) Å [91], i.e., the diff-

<table>
<thead>
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<tbody>
<tr>
<td>(1,0)</td>
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<tr>
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</tr>
<tr>
<td>(26,26)</td>
<td>0.31</td>
<td>22.95</td>
</tr>
</tbody>
</table>
ference is about 7%. As is mentioned above the overestimations in the structural parameter is characteristic for the quasi-classical approach. However, at least partially, this overestimation seems to be related with expansion of lattice of the single hexagonal layer (plane or cylindrical) if compared with that of the three-dimensional layered crystal.

It is also instructive to analyze the obtained spread of the molar zero-point vibration energy of BN nanotubes (0.25-0.33) eV and, in particular, its limit for ultra-large-radius tubes 0.31 eV using the data available on the vibration characteristics of h-BN layered crystal. The vibration energies of an isolated tubular layer and layered crystals can be directly compared as the atoms of the low-dimensional system can execute vibrations in three independent directions in physical space. Our quasi-classical estimations made for BN nanotubes agree well with analogous calculations (but in tight-binding approximation) for BN plane sheet of 0.27, the semiempirical estimate of 0.23 for zero-point vibrations energy in h-BN, and the estimate of 0.35 eV/mole from the theoretical phonon spectrum (see Subsection 2.2).

We have found that the binding energies of BN single-walled nanotubes corrected with zero-point vibration energies lies within the interval (12.01-29.39) eV. In particular, the calculated corrected binding energy of the ultra-large-radius tube is predicted as 22.95 eV. Previous quasi-classical calculations (but in tight-binding approximation) performed for BN isolated plane sheet have given the binding energy 23.00 eV/mole, which coincides in order of magnitude with this interval and agrees very well with present result obtained for large tubes. As it was demonstrated in Subsection 2.2, for its part the binding energy ~23 eV/mole for single-layer boron nitride structures should be in good agreement with binding energy data available for BN multi-layered structures. Summarizing the obtained results, it should be emphasized that a complex dependence of the BN nanotube molar binding energy on its radius is found out, though all the binding energy values are found to be positive, i.e., all tubes should be stable. However, they have rather different degrees of stability.

On the one hand, ultra-small-radius BN nanotubes (1,0) and (2,0) seem to be meta-stable, though their molar binding energies are positive, they are less than that for isolated hexagonal boron nitride layer. Especially the smallest (1,0) tube structure degenerated in zigzag atomic strip should be meta-stable because its binding energy is only about half of this value. Such a structure can be realized only as an inner wall in a multi-walled tube. On the other hand, the formation probabilities for BN tubes with indexes (1,1), (3,0), and (4,0) should exceed that for isolated sheet. Among them the (3,0) tube is well pronounced, formation of which is predicted to be energetically most preferable than the layer growth. Molar binding energies for other BN nanotubes slightly exceed that of sheet and their formation probabilities should be almost same as for layered crystal growth.

Finally, it should be noted that, in addition to the energy considerations concerning the relative stability of tubular structure, it is also necessary to take into account features characteristic to BN nanosystems, in view of the general equations derived for energy fluctuations of small completely open (incompressible) systems [112]. They show that the fluctuations should be unusually large because there are no constraints on the size of a system and, in addition, the fluctuations of the total or partial number of atoms in binary systems indirectly contribute to the fluctuations in their energy.

7. Acknowledgements

L. Chkhartishvili acknowledges the financial support from the Georgia National Science Foundation (GNSF) under the Project # GNSF/ST 08/4-411-Geometry of the boron nitride nanostructures.

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